

ST - 1KA · ST - 1KB

The ST - 1KA and 1KB are high - sensitivity NPN silicon phototransistors mounted in durable, hermetically sealed TO - 18 metal cans, which provide years of reliable performance, even under demanding conditions such as use outdoors.

FEATURES

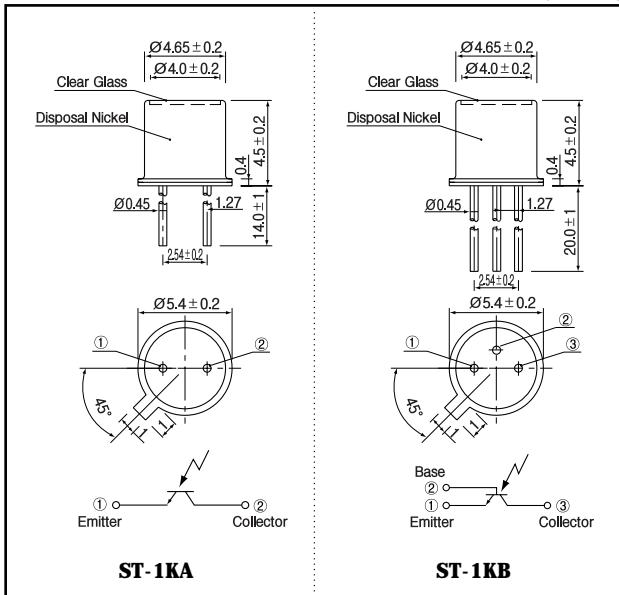
- Wide angular response
- Durable
- High reliability in demanding environments
- Two leads (Collector, Emitter) ST - 1KA
- Three leads (Collector Emitter, Base) ST - 1KB

APPLICATIONS

- Optical counters
- Optical detectors
- Infrared sensors
- Fiber optic communications

DIMENSIONS

(Unit : mm)

**MAXIMUM RATINGS**

(Ta=25 °C)

Item	Symbol	Rating	Unit
C - E voltage	V _{CEO}	40	V
E - C voltage	V _{ECD}	4	V
Collector current	I _C	50	mA
Collector power dissipation	P _C	150	mW
Operating temp.	T _{opr.}	- 30 ~ +100	
Storage Temp.	T _{stg.}	- 50 ~ +150	
Soldering temp. ¹⁾	T _{sol.}	260	

¹⁾For MAX.5 seconds at the position of 2 mm from the package

ELECTRO-OPTICAL CHARACTERISTICS

(Ta=25 °C)

Item	Symbol	Conditions	Min.	Typ.	Max.	Unit.
Collector dark current	I _{CEO}	V _{CEO} =10V		1	200	nA
Light current	I _L	V _{CE} =10V, 200lx ²	0.5	2.0	5.0	mA
C - E saturation voltage	V _{CE(sat)}	I _C =2mA, 2,000lx ²		0.2	0.4	V
Switching speeds	Rise time Fall time	V _{CC} =10V, I _C =5mA, R _L =100		0.8 10		μsec. μsec.
Spectral sensitivity				500~1,050		nm
Peak wavelength	p			880		nm
Half angle				± 50		deg.

²⁾ Color temp.=2856K standard Tungsten lamp

Photo transistors

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